

PART NUMBER 74HC239N-ROCV

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



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- Designed Specifically for High-Speed Memory Decoders and Data Transmission Systems
- Incorporates 2 Enable Inputs to Simplify Cascading and/or Data Reception
- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil **DIPs**
- Dependable Texas Instruments Quality and Reliability

description

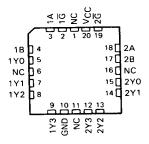
The 'HC239 circuit is designed to be used in high-performance memory-decoding or datarouting applications requiring very short propagation delay times. In high-performance memory systems this decoder can be used to minimize the effects of system decoding. When employed with high-speed memories utilizing a fast enable circuit, the delay times of this decoder and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The 'HC239 is comprised of two individual twoline to four-line decoders in a single package. The active-low enable input can be used as a data line in demultiplexing applications. These decoders/demultiplexers feature fully buffered inputs, each of which represents only one normalized load to its driving circuit.

SN54HC239 . . . J PACKAGE SN74HC239 . . . D[†] OR N PACKAGE (TOP VIEW)

1 \overline G 🔲	1	U 16		Vcc
1 A 🗌	2	15	D	2G
1B 🛚	3	14	р	2A
1Y0 🗌	4	13	р	2B
1Y1 🗌	5	12		2Y0
1Y2 🗌	6	11	₽	2Y1
1Y3 🗌	7	10		2Y2
GND [8	9		2Y3

SN54HC239 . . . FK PACKAGE (TOP VIEW)

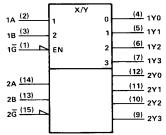


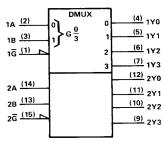
NC-No internal connection

[†]Contact the factory for D availability

The SN54HC239 is characterized for operation over the full military temperature range of ~55 °C to 125 °C. The SN74HC239 is characterized for operation from -40°C to 85°C.

logic symbols (alternatives)‡





[‡]These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for D, J, and N packages.

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



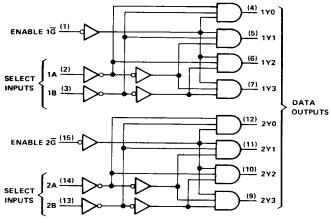
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HCMOS Devices

logic diagram (positive logic)



Pin numbers shown are for D, J, and N packages.

FUNCTION TABLE

INP	UTS	OUTDUTE						
ENABLE	SEL	ECT	OUTPUTS					
Ğ	В	Α	YO	Y1	Y2	Υ3		
Н	X	Х	L	L	L	L		
L	L	L	Н	L	L	L		
L	L	H	L	Н	L	L		
L	н	L	L	L	н	L		
L	Н	н	L	L	L	н		

absolute maximum ratings over operating free-air temperature range†

Supply voltage, VCC
Input clamp current, IjK (VI < 0 or VI > VCC) ±20 mA
Output clamp current, IOK (VO < 0 or VO > VCC) ±20 mA
Continuous output current, IO (VO = 0 to VCC)
Continuous current through VCC or GND pins
Lead temperature 1,6 mm (1/16 in) from case for 60 s: FK or J package 300 °C
Lead temperature 1,6 mm (1/16 in) from case for 10 s: D or N package
Storage temperature range65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



SN54HC239, SN74HC239

recommended operating conditions

			SN54HC239		SN74HC239			UNIT	
			MIN	NOM	MAX	MIN	NOM	MAX	Civili
Vcc	Supply voltage		2	5	6	2	5	6	>
VIH	High-level input voltage	V _{CC} = 2 V V _{CC} = 4.5 V V _{CC} = 6 V	1.5 3.15 4.2			1.5 3.15 4.2		,	٧
VIL	Low-level input voltage	V _{CC} = 2 V V _{CC} = 4.5 V V _{CC} = 6 V	0 0		0.3 0.9 1.2	0		0.3 0.9 1.2	٧
٧ı	Input voltage		0		VCC	0		Vcc	V
Vo	Output voltage		0		Vcc	0		VCC	٧
tt	Input transition (rise and fall) times	V _{CC} = 2 V V _{CC} = 4.5 V V _{CC} = 6 V	0 0		1000 500 400	0 0 0		1000 500 400	ns
TA	Operating free-air temperature		- 55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TA = 25°C		SN54HC239		SN74HC239		UNIT	
		Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONL
		2 V	1.9	1.998		1.9		1.9		
	$V_i = V_{iH}$ or V_{iL} , $I_{OH} = -20 \mu A$	4.5 V	4.4	4.499		4.4		4.4		
VoH	, ,,, ,, ,,,	6 V	5.9	5.999		5.9		5.9		V
YOH	V _I = V _{IH} or V _{IL} , I _{OH} = -4 mA	4.5 V	3.98	4.30		3.7		3.84		
	V _I = V _{IH} or V _{IL} , I _{OH} = 5.2 mA	6 V	5.48	5.80		5.2		5.34		
		2 V		0.002	0.1		0.1		0.1	
	V _I = V _{IH} or V _{II} , I _{OL} = 20 µA	4.5 V		0.001	0.1	Į.	0.1	ļ	0.1	
VOL	' "' "	6 V		0.001	0.1		0.1		0.1	V
02	VI = VIH or VIL, IOL = 4 mA	4.5 V		0.17	0.26		0.4	1	0.33	
	V _I = V _{IH} or V _{IL} , I _{OL} = 5.2 mA	6 V		0.15	0.26		0.4		0.33	
1į	V _I = V _{CC} or 0	6 V		±0.1	± 100		± 1000		±1000	nΑ
Icc	V _I = V _{CC} or 0, I _O = 0	6 V			8		160		80	μΑ
Ci		2 to 6 V		3	10	Ţ.	10		10	pF

switching characteristics over recommended operating free-air temperature range (unless otherwise noted), CL = 50 pF (see Note 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	vcc	TA = 25°C		SN54HC239	SN74HC239	UNIT
				MIN TYP	MAX	MIN MAX	MIN MAX	Oil
		A or B Y	2 V	62	150	225	190	ns
tnd	A or B		4.5 V	18	30	45	38	
t _{pd} A or B			6 V	14	26	38	32	
			2 V	53	120	180	150	ns
^t pd	G	Y	4.5 V	14	24	36	30	
pu			6 V	11	20	31	26	
			2 V	38	75	110	95	
^t pd		Y	4.5 V	8	15	22	19	ns
			6 V	6	13	19	16	}

Cpd	Power dissipation capacitance per decoder	No load, TA = 25°C	25 pF typ

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.



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